

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









GS6150 Multi-Rate 6G UHD-SDI Reclocker

Gennum Products

Key Features

- SMPTE ST 2081, ST 424, ST 292, and ST 259-C compliant
- Supports retiming data at rates of 125Mb/s, 270Mb/s, 1.485 and 1.485/1.001Gb/s, 2.97 and 2.97/1.001Gb/s, 5.94 and 5.94/1.001Gb/s
- Supports retiming of DVB-ASI signals
- Automatic or Manual Rate Selection
 - Detected rate indication in Auto Mode
- 4:1 input selector patented technology
- · Option of two reclocked data outputs
- Four configurable GPIO pins with ability to output device status, including:
 - Lock Detect
 - Loss of Signal (LOS)
 - Low/High bit-rate indication for slew-rate control of SDI cable drivers
- On-chip 100Ω differential input and output termination
- Bypass support for rates up to 5940Mb/s
 - Manual Bypass function
 - Configurable automatic Bypass when not locked
- Option to use external reference or operate referenceless
- Cascading reference buffer supports multiple reclockers using a single reference source
- Input signal equalization and output signal de-emphasis to compensate for trace dielectric losses
- Single power supply operation at 1.8V
- 130mW typical power consumption (150mW with second output enabled)
- Pb-free and RoHS compliant
- Operating temperature range: -40°C to 85°C

Applications

- SMPTE ST 2081, SMPTE ST 424,
 SMPTE ST 292, SMPTE ST 259-C coaxial cable serial digital interfaces
- EN50083-9 DVB-ASI interfaces
- MADI standard

Description

The GS6150 is a low-power, multi-rate serial digital reclocker designed to automatically recover the embedded clock from a digital video signal and re-time the incoming video data.

The GS6150 will recover the embedded clock signal and retime the data from 6G UHD-SDI signals compliant with SMPTE ST 2081. In addition, it can also re-time SMPTE ST 259-C, SMPTE ST 292, SMPTE ST 424 or DVB-ASI compliant digital video signals as well as MADI audio streams.

The GS6150 features four high-speed differential signal inputs feeding a 4:1 input selector. Input termination is on-chip for seamless matching to 100Ω differential transmission lines. The input selector is a component of a video switching system with tightly constrained timing requirements.

The GS6150 includes programmable trace equalization to compensate for high-frequency losses associated with board-level interconnect.

Two CML outputs interface seamlessly to devices with a CML input reference between 1.2V and 2.5V.

Programmable output swing and de-emphasis provide flexibility in managing signal integrity of the output signals.

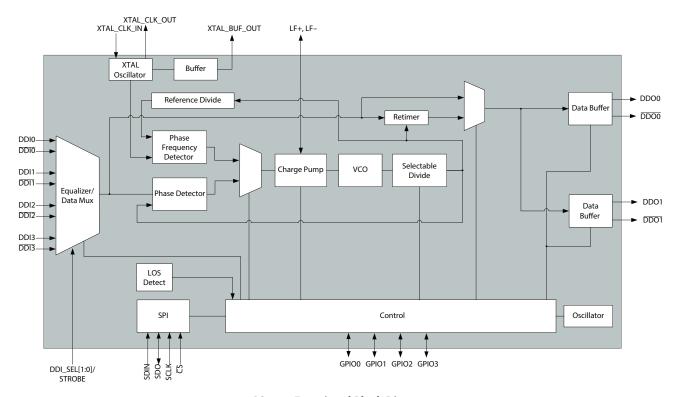
The GS6150 can operate in either automatic rate detection or manual rate selection mode. In auto mode the device will automatically detect and lock onto incoming data signals at any supported rate.

The device can operate without an external 27MHz frequency reference. For applications which require rapid signal lock, an external 27MHz reference may be used to set the VCO frequency when not locked to the input signal. The presence of an external reference crystal is automatically detected by the device.

In systems that require passing of non-supported data rates, the GS6150 can be configured to either automatically or manually enter a bypass mode in order to pass the signal without reclocking.

A four-wire serial Gennum Serial Peripheral Interface (GSPI) facilitates configuration and status monitoring of the device. Multiple GS6150 devices can be daisy-chained together with a single 4-pin connection to the host system.

This device is Pb-free, and the encapsulation compound does not contain halogenated flame retardant. This component and all homogenous sub-components are RoHS compliant.



GS6150 Functional Block Diagram

Revision History

Version	ECO	PCN	Date	Changes and/or Modifications
2	024967	_	March 2015	Updated Table 2-2 and Table 2-3. Updated Section 4.11 and Section 5. Updated to Final Data Sheet.
1	022115	_	September 2014	Changed product title. Updated Table 5-1 format. Updates throughout Table 2-2 and Table 2-3. Added Section 4.5.5. Updated Table 5-1.
0	016784	_	December 2013	New Document

Contents

1. Pin Out	5
1.1 Pin Assignment	5
1.2 Pin Descriptions	6
2. Electrical Characteristics	10
2.1 Absolute Maximum Ratings	10
2.2 DC Electrical Characteristics	10
2.3 AC Electrical Characteristics	12
3. Input/Output Circuits	15
4. Detailed Description	17
4.1 Serial Data Inputs	17
4.1.1 Input Trace Equalization	17
4.1.2 Input Selection	17
4.2 Reference Clock	19
4.3 Signal Monitoring	19
4.3.1 Loss of Signal Detection	19
4.3.2 Lock Detection	21
4.3.3 Rate Detection	22
4.3.4 Low/High Bit Rate Detection for Slew Rate Control	23
4.4 Low Power Modes	23
4.5 Serial Data Output	24
4.5.1 Output Impedance	24
4.5.2 Output Signal Interface Levels	24
4.5.3 Adjustable Output Swing	24
4.5.4 Output De-emphasis	25
4.5.5 Output Common Mode Voltage	26
4.6 Output Mute, Disable, and Data Selection	26
4.7 Bypass Mode	27
4.8 DVB-ASI	27

4.9 Device Power Up	27
4.9.1 Power on Reset (POR)	27
4.9.2 Reset Pin (RST)	27
4.10 GPIO Pins Configuration	27
4.11 GSPI Host Interface	29
4.11.1 CS Pin	29
4.11.2 SDIN Pin	29
4.11.3 SDOUT Pin	29
4.11.4 SCLK Pin	31
4.11.5 Command Word Description	31
4.11.6 GSPI Transaction Timing	34
4.11.7 Single Read/Write Access	36
4.11.8 Auto-increment Read/Write Access	37
4.11.9 Setting a Device Unit Address	38
4.11.10 Default GSPI Operation	39
5. Host Interface Register Map	41
6. Typical Application Circuit	60
7. Package and Ordering Information	61
7.1 Package Dimensions	61
7.2 Recommended PCB Footprint	62
7.3 Packaging Data	62
7.4 Marking Diagram	63
7.5 Solder Reflow Profile	63
7.6 Ordering Information	63

1. Pin Out

1.1 Pin Assignment

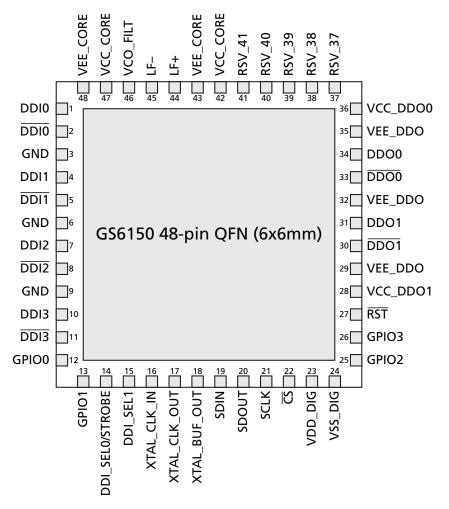


Figure 1-1: GS6150 Pin Out

1.2 Pin Descriptions

Table 1-1: GS6150 Pin Descriptions

Pin Number	Name	Туре	Description
1, 2	DDI0, DDI0	Input	Serial Digital Differential Input 0.
3, 6, 9	GND	Power	Input channel isolation. Connect to ground or leave unconnected
4, 5	DDI1, DDI1	Input	Serial Digital Differential Input 1.
7,8	DDI2, DDI2	Input	Serial Digital Differential Input 2.
10, 11	DDI3, DDI3	Input	Serial Digital Differential Input 3.
12	GPIO0	Digital Input/Output	Multi-function Control/Status Input/Output 0. Signal options are: LOS (output; default) LOCKED LBR_HBR RATE_DET0 RATE_DET1 RATE_DET2 LOCKED_125M LOCKED_270M LOCKED_1G485 LOCKED_2G97 LOCKED_5G94 RATE_CHANGE DD00_DISABLE DD01_DISABLE This pin is configured using the GPIO0_SELECT and GPIO0_IO_SELECT bits in the GPIO_CONTROL_REG_0 register.
13	GPIO1	Digital Input/Output	Multi-function Control/Status Input/Output 1. Signal options are: LOS LOCKED (output; default) LBR_HBR RATE_DET0 RATE_DET1 RATE_DET2 LOCKED_125M LOCKED_270M LOCKED_16485 LOCKED_2697 LOCKED_5G94 RATE_CHANGE DDO0_DISABLE DDO1_DISABLE This pin is configured using the GPIO1_SELECT and GPIO1_IO_SELECT bits in the GPIO_CONTROL_REG_0 register.

Table 1-1: GS6150 Pin Descriptions (Continued)

Pin Number	Name	Туре	Description
14, 15	DDI_SEL0/STROBE, DDI_SEL1	Logic Input	Input selection control. Used to select the high-speed input for processing through the device. Refer to Table 4-1 for details on input selection.
16	XTAL_CLK_IN	Input	Reference Crystal Pin/27MHz clock input. Connect to an external circuit as shown in Figure 6-1: GS6150 Typical Application Circuit or to a digital clock source (XTAL_BUF_OUT of another GS6150 or GS6151). Connect to ground if operating referenceless.
17	XTAL_CLK_OUT	Output	Reference Crystal Pin. Connect to a external circuit as shown in Figure 6-1: GS6150 Typical Application Circuit, or leave unconnected if XTAL_CLK_IN is driven by an external clock source or if XTAL_CLK_IN is connected to ground (referenceless).
18	XTAL_BUF_OUT	Output	Buffered clock reference output. Leave unconnected if not used to drive 27MHz clock input of another device.
19	SDIN	Digital Input	Serial digital data input for the Gennum Serial Peripheral Interface (GSPI) host control/status port. Refer to 4.11 GSPI Host Interface for more details.
20	SDOUT	Digital Output	Serial digital data output for the Gennum Serial Peripheral Interface (GSPI) host control/status port. Refer to 4.11 GSPI Host Interface for more details.
21	SCLK	Digital Input	Burst-mode clock input for the Gennum Serial Peripheral Interface (GSPI) host control/status port. Refer to 4.11 GSPI Host Interface for more details.
22	CS	Digital Input	Chip select input for the Gennum Serial Peripheral Interface (GSPI) host control/status port. Active-low input. Refer to 4.11 GSPI Host Interface for more details.
23	VDD_DIG	Power	Most positive power supply for the internal logic Connect to 1.8V.
24	VSS_DIG	Power	Most negative power supply for the internal logic Connect to ground.

Table 1-1: GS6150 Pin Descriptions (Continued)

Pin Number	Name	Туре	Description
25	GPIO2	Digital Input/Output	Multi-function Control/Status Input/Output 2. Signal options are: LOS LOCKED LBR_HBR (output; default) RATE_DET0 RATE_DET1 RATE_DET1 RATE_DET2 LOCKED_125M LOCKED_270M LOCKED_16485 LOCKED_16485 LOCKED_2697 LOCKED_5G94 RATE_CHANGE DDO0_DISABLE DDO1_DISABLE
26	GPIO3	Digital Input/Output	This pin is configured using the GPIO2_SELECT and GPIO2_IO_SELECT bits in the GPIO_CONTROL_REG_1 register. Multi-function Control/Status Input/Output 3. Signal options are: LOS LOCKED LBR_HBR RATE_DET0 RATE_DET1 RATE_DET2 LOCKED_125M LOCKED_270M LOCKED_270M LOCKED_16485 LOCKED_2697 LOCKED_5G94 RATE_CHANGE DDO0_DISABLE DDO1_DISABLE (input; default) This pin is configured using the GPIO3_SELECT and GPIO3_IO_SELECT bits in the GPIO_CONTROL_REG_1 register.
27	RST	Digital Input	Reset pin. If set LOW, all blocks set to default conditions and inputs/outputs set to high impedance. If HIGH, normal operation of the device resumes. By default, internally pulled HIGH.
28	VCC_DDO1	Power	Most positive power supply connection for the DDO1/ $\overline{DDO1}$ output driver. Connect to any voltage between 1.2V and 2.5V.
29, 32, 35	VEE_DDO	Power	Most negative power supply connections for the output drivers. Connect to ground.
30, 31	DDO1, DDO1	Output	Differential serial data output 1.
33, 34	DDO0, DDO0	Output	Differential serial data output 0.
36	VCC_DDO0	Power	Most positive power supply connection for the DDO0/DDO0 output driver. Connect to any voltage between 1.2V and 2.5V.

Table 1-1: GS6150 Pin Descriptions (Continued)

Pin Number	Name	Туре	Description
37	RSV_37	Power Decoupling	Connect through decoupling capacitor to ground.
38	RSV_38	Power	Connect to 1.8V.
39	RSV_39	Power	Connect to ground.
40, 41	RSV_40, RSV_41	Input	Leave unconnected.
42	VCC_CORE	Power	Most positive power supply connection to the analog core Connect to 1.8V.
43	VEE_CORE	Power	Most negative power supply connection to the analog core Connect to ground.
44	LF+	Passive	Connect to LF– through C _{LF} Refer to Figure 6-1: GS6150 Typical Application Circuit.
45	LF-	Passive	Connect to LF+ through C _{LF} Refer to Figure 6-1: GS6150 Typical Application Circuit.
46	VCO_FILT	Power	External decoupling for the VCO. Refer to Figure 6-1: GS6150 Typical Application Circuit.
47	VCC_CORE	Power	Most positive power supply connection for the analog core Connect to 1.8V.
48	VEE_CORE	Power	Most negative power supply connection to the analog core Connect to ground.
_	Center Pad	Power	Ground pad on bottom of package.

2. Electrical Characteristics

2.1 Absolute Maximum Ratings

Table 2-1: Absolute Maximum Ratings

Parameter	Value
Supply Voltage – Core (VCC_CORE, VDD_DIG)	-0.5 to +2.1V _{DC}
Supply Voltage – Output Driver (VCC_DDO0, VCC_DDO1)	-0.5 to +2.8V _{DC}
Input ESD Voltage	4kV
Storage Temperature Range (T _S)	–50°C to +125°C
Operating Temperature Range (T _A)	-40°C to +85°C
Input Voltage Range (any input pin)	-0.3 to (V _{CC_CORE} + 0.3)V _{DC}
Solder Reflow Temperature	+260°C

Note: Absolute Maximum Ratings are those values beyond which damage may occur. Functional operation outside of the ranges shown in the AC/DC electrical characteristics tables is not guaranteed.

2.2 DC Electrical Characteristics

Table 2-2: DC Electrical Characteristics

VCC_CORE, VDD_DIG = $+1.8V \pm 5\%$, $T_A = -40$ °C to +85°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Тур	Max	Units	Notes
Supply Voltage – Core (VCC_CORE, VDD_DIG)	V _{CC_CORE} , V _{DD_DIG}	_	1.710	1.8	1.890	V	
Supply Voltage – Output Driver (VCC_DDO0, VCC_DDO1)	V _{CC_DDO0} , V _{CC_DDO1}	_	1.140	_	2.625	V	

Table 2-2: DC Electrical Characteristics (Continued)

VCC_CORE, VDD_DIG = $+1.8V \pm 5\%$, $T_A = -40$ °C to +85°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Тур	Max	Units	Notes
		Data Rate 6G, DDO1/DDO1 disabled	_	140	185	mW	1, 2
		Data Rate <6G, DDO1/DDO1 disabled	_	130	170	mW	1, 2
Power	P_{D}	Data Rate 6G, Default Settings, DDO1/DDO1 enabled	_	210	280	mW	3, 4
	-	Data Rate <6G, Default Settings, DDO1/DDO1 enabled	_	190	255	mW	3, 4
		Maximum Supply and Power Settings	_	280	360	mW	5
Power (Sleep operation)	P _{SLEEP}	_	_	20	35	mW	
Power (Standby operation)	P _{STANDBY}	_	_	80	110	mW	
Supply Current - Output Driver		Output Swing Register Setting = 0000 _b	_	4.8	7	mA	6, 7
	I _{CC_DD00} , I _{CC_DD01}	Output Swing Register Setting= 0100 _b	_	7.5	12	mA	6, 7
		Output Swing Register Setting = 1100 _b	_	15	22	mW mW mW mW mW	6, 7
		Output De-emphasis Disabled Data Rate 6G	_	82	_	mA	8
Supply Current - Core	I _{CC_CORE}	Output De-emphasis Disabled Data Rate 3G	_	74	_	mA	8
		Output De-emphasis Enabled Data Rate 6G	_	90	_	mA	8
		Output De-emphasis Enabled Data Rate 3G	_	81	_	mA	8
Supply Current - Digital	I _{CC_DIG}	External Crystal Referenced	_	7	12	mA	
Serial Input Termination		Differential	75	100	125	Ω	
Serial Output Termination		Differential	75	100	125	Ω	
Serial Input Common Mode Voltage	V _{CMIN}	_	0.9	_	V _{CC_CORE} - 50mV	V	9, 10

GS6150
Final Data Sheet Rev.2
PDS-060127 March 2015

www.semtech.com

Table 2-2: DC Electrical Characteristics (Continued)

VCC_CORE, VDD_DIG = $+1.8V \pm 5\%$, $T_A = -40$ °C to +85°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Тур	Max	Units	Notes
Input Voltage - Digital Pins (CS, SDIN, CLK, GPIO[0:3])	V_{IH}	_	0.65* VDD_DIG	_	VDD_DIG	V	
	V _{IL}	_	0	_	0.35* VDD_DIG	V	
Output Voltage - Digital Pins (SDOUT, GPIO[0:3])	V _{OH}	I _{OH} = -2mA	VDD_DIG - 0.45	_	_	V	
	V _{OL}	I _{OL} = 2mA	_	_	0.45	٧	

Notes:

- 1. Normal operation in referenceless mode, minimum output swing with de-emphasis disabled
- 2. VCC_DDO0/1 = 1.2V
- 3. The swing is default and de-emphasis is on
- 4. VCC_DDO0/1 = 1.8V
- 5. DDO0/DDO0 and DDO1/DDO1 set to maximum swing setting, external crystal reference used
- 6. Consumption per enabled DDO output
- 7. Refer to Table 4-3 for the exact register settings for each ΔV_{DDO} output swing listed
- 8. For two enabled outputs
- 9. Maximum input voltage level = $1.8V \pm 5\%$
- 10. Up to a maximum swing of 800mV

2.3 AC Electrical Characteristics

Table 2-3: AC Electrical Characteristics

VCC_CORE, VDD_DIG = $+1.8V \pm 5\%$, $T_A = -40$ °C to +85°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Тур	Max	Units	Notes
Input Data Rate (Bypass)	DR _{BYPASS}	Bypass mode enabled	3	_	5940	Mb/s	1
Input Sensitivity	ΔV_{SDI}	Differential	200	_	800	mV_{ppd}	
Output Valtage Swing	AV	Output Swing Register Setting = 0100 _b	310	410	510	${\sf mV}_{\sf ppd}$	2
Output Voltage Swing	$\Delta V_{ m DDO}$	Output Swing Register Setting = 1100 _b	600	800	1000	${\sf mV}_{\sf ppd}$	2
Serial Input Jitter Tolerance	IJT	Square wave modulation	0.8	_	_	UI	
		Referenceless	_	_	50	ms	
PLL Lock Time — Asynchronous	t _{ALOCK}	With External Reference (MADI enabled)	_	_	30	ms	
,		With External Reference (MADI disabled)	_	_	20	ms	

GS6150 www.semtech.com 12 of 64

Proprietary & Confidential

Table 2-3: AC Electrical Characteristics (Continued)

VCC_CORE, VDD_DIG = $+1.8V \pm 5\%$, $T_A = -40$ °C to +85°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Тур	Max	Units	Notes
PLL Lock Time — Synchronous	^t slock	Referenceless	_	_	10	μs	
		With External Reference	_	_	10	μs	
Serial Data (DDO0 and DDO1) Output Rise And Fall Time	t _{riseDDO}	$20\% \sim 80\%$ rising edge into 50Ω load	_	_	70	ps	
	t _{fallDDO}	$20\% \sim 80\%$ falling edge into 50Ω load	_	_	70	ps	
Rise And Fall Time Mismatch (DDO0 and DDO1)	_	_	_	_	15	ps	
Duty Cycle Distortion	_	Data Rate 6G	_	_	10	%	
(DDO0 and DDO1)	_	Data Rate < 6G	_	_	5	%	
	t _{OJ(125Mb/s)}		_	0.02	0.03	UI _{P-P}	3, 4
	t _{OJ(270Mb/s)}		_	0.02	0.03	UI_{P-P}	3, 4
Serial Data Output Jitter	t _{OJ(1485Mb/s)}	BW = Nominal	_	0.03	0.06	UI_{P-P}	3, 4
Intrinsic	t _{OJ(2970Mb/s)}	PRN 2 ²³ – 1 test pattern	_	0.04	0.09	UI _{P-P}	3, 4
	t _{OJ(5940Mb/s)}	-	_	0.07	0.13	UI _{P-P}	3, 4
	t _{OJ(BYPASS)}	-	_	0.06	0.09	UI _{P-P}	3, 4
PLL Loop Bandwidth -	BW _{LOOP} (125Mb/s)	PLL_LOOP_BANDWIDTH = 00001	_	37	_	kHz	
		PLL_LOOP_BANDWIDTH = 00010	_	74	_	kHz	
		PLL_LOOP_BANDWIDTH = 00100 (default)	_	148	_	kHz	
		PLL_LOOP_BANDWIDTH = 01000	_	296	_	kHz	
		PLL_LOOP_BANDWIDTH = 10000	_	590	_	kHz	
	BW _{LOOP} (270Mb/s)	PLL_LOOP_BANDWIDTH = 00001	_	80	_	kHz	
		PLL_LOOP_BANDWIDTH = 00010	_	160	_	kHz	
		PLL_LOOP_BANDWIDTH = 00100 (default)	_	320	_	kHz	
		PLL_LOOP_BANDWIDTH = 01000	_	640	_	kHz	
		PLL_LOOP_BANDWIDTH = 10000	_	1.28	_	MHz	

GS6150 Final Data Sheet Rev.2 PDS-060127

March 2015

www.semtech.com

Table 2-3: AC Electrical Characteristics (Continued)

VCC_CORE, VDD_DIG = $+1.8V \pm 5\%$, $T_A = -40$ °C to +85°C unless otherwise specified

Parameter	Symbol	Conditions	Min	Тур	Max	Units	Notes
	BW _{LOOP} (1485Mb/s)	PLL_LOOP_BANDWIDTH = 00001	_	438	_	kHz	
		PLL_LOOP_BANDWIDTH = 00010	_	875	_	kHz	
		PLL_LOOP_BANDWIDTH = 00100 (default)	_	1.75	_	MHz	
		PLL_LOOP_BANDWIDTH = 01000	_	3.5	_	MHz	
		PLL_LOOP_BANDWIDTH = 10000	_	7	_	MHz	
	BW _{LOOP} (2970Mb/s)	PLL_LOOP_BANDWIDTH = 00001	_	875	_	kHz	
		PLL_LOOP_BANDWIDTH = 00010	_	1.75	_	MHz	
PLL Loop Bandwidth		PLL_LOOP_BANDWIDTH = 00100 (default)	_	3.5	_	MHz	
		PLL_LOOP_BANDWIDTH = 01000	_	7.0	_	MHz	
		PLL_LOOP_BANDWIDTH = 10000	_	14.0	_	MHz	
	BW _{LOOP} (5940Mb/s)	PLL_LOOP_BANDWIDTH = 00001	_	1.75	_	MHz	
		PLL_LOOP_BANDWIDTH = 00010	_	3.5	_	MHz	
		PLL_LOOP_BANDWIDTH = 00100 (default)	_	7.0	_	MHz	
		PLL_LOOP_BANDWIDTH = 01000		14.0	_	MHz	
		PLL_LOOP_BANDWIDTH = 10000	_	28.0	_	MHz	

Note:

- 1. Edge detection method for LOS detection should be used for data rates below 20Mb/s
- 2. Refer to Table 4-3 for the exact register settings for each ΔV_{DDO} output swing listed
- 3. Jitter measured using an oscilloscope according to SMPTE RP-184
- 4. Accumulated jitter measured peak to peak differential over 2000 hits

Rev.2

3. Input/Output Circuits

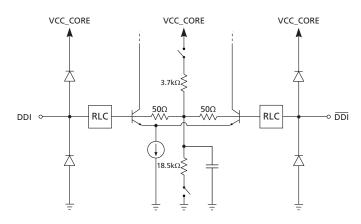


Figure 3-1: DDI0, DDI0, DDI1, DDI1, DDI2, DDI2, DDI3, DDI3 Serial Digital Differential Inputs

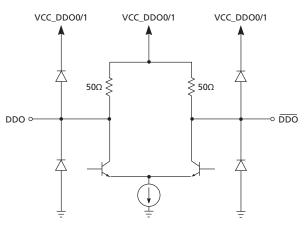


Figure 3-2: DD00, DD00, DD01, DD01 Serial Digital Differential Output

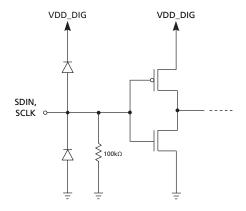


Figure 3-3: SDIN and SCLK

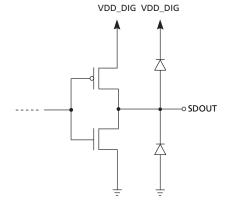


Figure 3-4: SDOUT

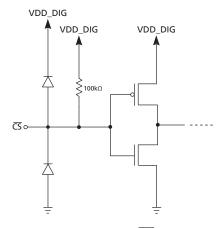


Figure 3-5: CS

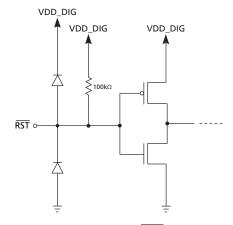


Figure 3-6: RST

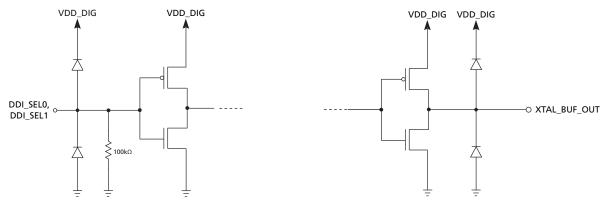


Figure 3-7: DDI_SEL0/STROBE and DDI_SEL1

Figure 3-8: XTAL_BUF_OUT

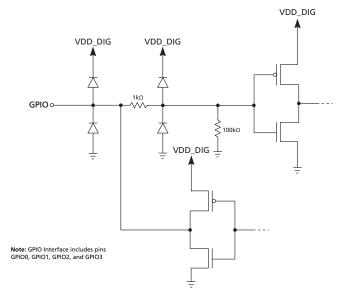


Figure 3-9: General Purpose Inputs/Outputs (GPIO)

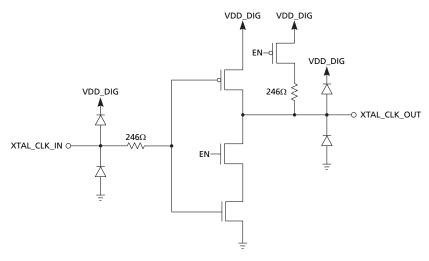


Figure 3-10: XTAL_CLK_IN and XTAL_CLK_OUT

www.semtech.com

4. Detailed Description

The GS6150 is a multi-standard reclocker for serial digital SDTV SDI and DVB-ASI signals operating at 270Mb/s, HDTV SDI signals operating at 1.485Gb/s and 1.485/1.001Gb/s, 3G SDI signals operating at 2.97Gb/s and 2.97/1.001Gb/s, and 6G UHD-SDI signals operating at 5.94Gb/s and 5.94/1.001Gb/s and MADI audio streams at 125Mb/s.

4.1 Serial Data Inputs

The GS6150 features four 100Ω terminated differential input buffers.

A serial data input signal may be connected to any of the following input pin pairs of the device: $DDIO/\overline{DDIO}$, $DDI1/\overline{DDI1}$, $DDI2/\overline{DDI2}$, and $DDI3/\overline{DDI3}$.

By default, the self-biasing circuit at the input is enabled to allow AC coupling to upstream devices. To enable DC coupling of the inputs, the user must disable the self-biasing network by setting bits 4:4 through 5:5 to 0 in the register 7_h: DDI[0:1]_TRACE_EQ_DC_TERM_ENABLE.

In order to select DC coupling, please ensure that the output common mode of the upstream device is in range of the input common mode voltage range shown in Table 2-2.

The serial digital input buffer is capable of operation with any binary coded signal that meets the input signal level requirements defined below, with any data rate between 3Mb/s and 5.94Gb/s.

4.1.1 Input Trace Equalization

The GS6150 features adjustable trace equalization to compensate for PCB trace dielectric losses up to half the maximum supported data rate, or 3GHz. The equalization has three settings: the LOW (default) setting is optimized for compensating the high-frequency losses associated with 0-7dB of trace loss at 1.5GHz for data rates of 2.97Gb/s and below, and for 0-10dB of trace loss at 3GHz for 5.94Gb/s. The HIGH setting is optimized for trace loss between 7-14dB at 1.5GHz for data rates 2.97Gb/s and below. The 0dB or EQ_BYPASS setting may be used in systems with negligible trace loss. These settings are selected using the DDI0_TRACE_EQ_CONTROL, DDI1_TRACE_EQ_CONTROL and DDI3_TRACE_EQ_CONTROL bits in the INPUT_CONTROL_REG_0 register at address 5_h.

The default state of the device is input trace equalization on all inputs set to LOW.

4.1.2 Input Selection

The GS6150 incorporates a 4:1 input selector which allows the connection of four independent streams of video/data.

The selector is controllable in three separate ways:

GS6150 www.semtech.com
Final Data Sheet Rev.2
PDS-060127 March 2015

- 1. The DDI_SEL0 and DDI_SEL1 pins can be used to select the input.
- 2. A GSPI accessible register can be used to select the input, with the state change occurring as soon as the register value changes.
- 3. A GSPI accessible register can be used to select the input, with a rising edge on the STROBE pin triggering a change to the next state.

Since these states are mutually exclusive, the DDI_SEL0 pin is shared with the STROBE function.

In the case of using the DDI_SEL0/STROBE and DDI_SEL1 pins (#1 above) or the STROBE pre-select method (#3 above), the input selector will switch within 1µs of the change of state on the corresponding pin(s). This strict timing requirement is not maintained when using GSPI register selection (#2 above).

Each of the device's four inputs is selected as shown in Table 4-1.

Table 4-1: Pin and Register Settings for Input Selection

Regist	Pin Settings		Differential			
INPUT_SELECTION_CONTROL 7 _h [9:8]	DDI_SELECT 7 _h [11]	DDI_SELECT 7 _h [10]	DDI_SEL1	DDI_SEL0/ STROBE	High-speed Input Selected	
X0 (default)	Х	Х	LOW	LOW	DDI0, DDI0	
X0 (default)	Х	Х	LOW	HIGH	DDI1, DDI1	
X0 (default)	Х	Х	HIGH	LOW	DDI2, DDI2	
X0 (default)	Х	Х	HIGH	HIGH	DDI3, DDI3	
01	0	0	Х	Х	DDI0, DDI0	
01	0	1	Х	Х	DDI1, DDI1	
01	1	0	Х	Х	DDI2, DDI2	
01	1	1	Х	Х	DDI3, DDI3	
11	0	0	Х	on LOW-to- HIGH transition	DDI0, DDI0	
11	0	1	Х	on LOW-to- HIGH transition	DDI1, DDI1	
11	1	0	Х	on LOW-to- HIGH transition	DDI2, DDI2	
11	1	1	Х	on LOW-to- HIGH transition	DDI3, DDI3	

Note: 'X' indicates 'Do Not Care'

The DDI_SEL0/STROBE and DDI_SEL1 pins include internal pull-downs, which pulls the input voltage LOW if either pin is unconnected.

When using the STROBE pre-select method (#3 above), the pre-selected input buffer and trace EQ is powered up in advance of the STROBE pulse.

4.2 Reference Clock

The GS6150 can operate with or without an external frequency reference. For applications requiring rapid asynchronous locking, a 27MHz reference or crystal is required.

The PLL lock times for both referenceless and external crystal reference operation are given in Table 2-3: AC Electrical Characteristics.

If a reference is connected to the XTAL_CLK_IN pin or a crystal is connected to the XTAL_CLK_IN and XTAL_CLK_OUT pins of the device, it will automatically be used as the reference frequency for rapid asynchronous lock. If XTAL_CLK_IN is not connected to a crystal, XTAL_CLK_OUT must be left unconnected.

The XTAL_CLK_IN pin operates correctly when connected directly to the XTAL_BUF_OUT from another GS6150, or a 27MHz output of a different device.

4.3 Signal Monitoring

The GS6150 measures and reports the following signal status and quality monitoring parameters:

- Loss of Signal
- Lock Detection
- · Rate Detection
- · Low/High Bit Rate Detection

4.3.1 Loss of Signal Detection

LOS (Loss of Signal) detection is an active HIGH output available to the application on any of the GPIO[3:0] multi-function status and control pins. It is selected for output using the GPIO[3:0]_IO_SELECT and GPIO[3:0]_SELECT bits accessible in the GPIO_CONTROL_REG_0 and GPIO_CONTROL_REG_1 registers. It is the default output of the GPIO0 pin.

LOS indicates when the serial digital signal selected by the input selector is invalid. This function is always active.

Two methods can be used to detect loss of signal: strength (default) and edge. Either method can be selected with LOS_DETECTION_METHOD bits of register PLL_CONTROL.

When strength detection is used as the method of LOS detection the corresponding GPIO pin will be HIGH (signal lost) when the input signal amplitude within a predefined window falls below the threshold set by the bits DDI[0:3]_LOS_THRESHOLD_CONTROL in the LOS_CONTROL_REG_1 and LOS_CONTROL_REG_2 registers. The LOS threshold hysteresis can be set by the LOS_HYSTERESIS bits in the LOS_CONTROL_REG_0 register at address F_{h} .

The corresponding GPIO pin will be LOW (signal present) when the input signal amplitude within a predefined window is above the defined threshold.

GS6150
Final Data Sheet Rev.2
PDS-060127 March 2015

The method of strength detection is measurement of the average rectified differential voltage on the input pins. The strength detection method is therefore inherently dependent on the input signal's eye shape, particularly the rise/fall times of the input signal relative to the data rate. Additionally, the circuit has a lower bandwidth limit of operation (20Mb/s) below which it is recommended that the edge detection method is used. The absolute value of the threshold can be determined for any input swings according to Equation 4-1 below:

$$Threshold = \frac{1.9 \text{mV} \times (\text{DDI[0..3]_LOS_THRESHOLD_CONTROL}) \times 53}{(\text{DEVICE_SPECIFIC_LOS_THRESHOLD})}$$

Equation 4-1

where DEVICE_SPECIFIC_LOS_THRESHOLD specifies the LOS threshold value for a 100mV input swing at SD-rate specific to each device. The other rates scale according to the fractional relationship given in Figure 4-1 and Figure 4-2 below.

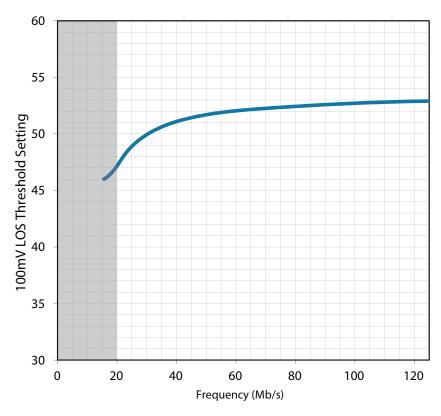


Figure 4-1: LOS Threshold at 100mV Input Swing vs. Low Frequency Rates for a Nominal DEVICE_SPECIFIC_LOS_THRESHOLD of 53

Note: Edge detection method is recommended for signals in shaded areas.

GS6150 www.semtech.com 20 of 64
Final Data Sheet Rev.2

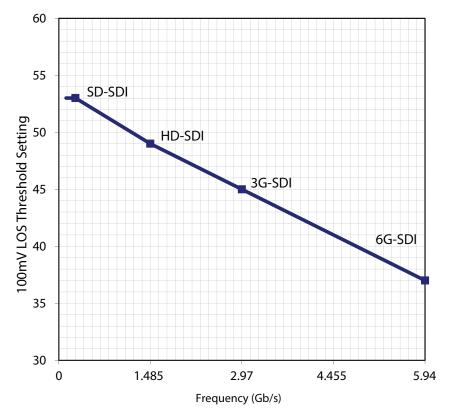


Figure 4-2: LOS Threshold at 100mV Input Swing vs. SDI Data Rates for a Nominal DEVICE SPECIFIC LOS THRESHOLD of 53

Strength detection is unaffected by the Trace EQ settings in INPUT_CONTROL_REG_0.

When edge detection is used as the method of LOS detection the corresponding GPIO pin will be HIGH (signal lost) when no transitions are detected on the selected input. The corresponding GPIO pin will be LOW (signal present) when transitions are detected on the input. The LOS status is also available through the LOS bit in the PLL_STATUS register, and as a sticky status through the LOS_STICKY bit in the STICKY_STATUS register at address 50_h.

4.3.2 Lock Detection

The GS6150 lock detection circuitry outputs a LOCKED status signal which indicates that the CDR has achieved phase lock to the incoming data stream. The LOCKED signal is an active HIGH output available to the application on any of the GPIO[3:0] multi-function status and control pins. It is selected for output using the GPIO[3:0]_IO_SELECT and GPIO[3:0]_SELECT bits accessible in the GPIO_CONTROL_REG_0 and GPIO_CONTROL_REG_1 registers. By default, LOCKED is output on GPIO1.

The LOCKED status is available from the LOCKED bit in the PLL_STATUS register, and the LOCK_LOST_STICKY bit in the STICKY_STATUS register indicates whether lock has been lost since the bit was last cleared.

To optimize systems with high DCD and/or high residual ISI the LOCK_SAMPLE bit of the PD_CONTROL register should be set to $1_{\rm b}$ in conjunction with reducing the Loop Bandwidth.

www.semtech.com

GS6150 Final Data Sheet Rev.2 PDS-060127 March 2015

4.3.2.1 Synchronous and Asynchronous Lock Time

Asynchronous lock time is defined as the time it takes the device to lock when a signal is first applied to the serial digital inputs, or when the signal rate changes.

The synchronous lock time is defined as the time it takes the device to lock to a signal which has been momentarily interrupted.

The asynchronous and synchronous lock times are defined in Table 2-3: AC Electrical Characteristics.

To qualify for synchronous lock time, the maximum interruption time of the signal is 10μ s for a 270Mb/s signal. 1.485Gb/s, 2.97Gb/s, and 5.94Gb/s signals, as well as their f/1.001 components have a maximum interruption time of 6μ s. The new signal, after interruption, must have the same frequency as the original signal but can have arbitrary phase.

4.3.3 Rate Detection

The GS6150 can be manually forced to lock to a specific supported data rate, or automatically search for and lock to supported rates. The selection between manual and automatic rate selection is through the FORCE_PLL_RATE and FORCE_PLL_RATE_ENABLE bits of the PLL_CONTROL register at address 4C_h. By default the device is set to automatically search for supported SDI rates.

When set to automatically detect supported data rates, the device repeatedly cycles through each supported rate that is enabled through the RATE_ENABLE_5G94, RATE_ENABLE_2G97, RATE_ENABLE_1G485, RATE_ENABLE_270M and RATE_ENABLE_125M bits of the PLL_CONTROL register, until the device phase locks to one of the enabled rates. If lock is lost the rate search resumes, continuously testing for each rate in sequence until lock is regained.

The device reports the current data rate setting of the automatic rate search state machine through the DETECTED_RATE bits in the PLL_STATUS register at address 4F_h. Each bit of DETECTED_RATE is also available to output through the GPIO pins, selected for output using the GPIO[3:0]_IO_SELECT and GPIO[3:0]_SELECT bits accessible in the GPIO_CONTROL_REG_0 register. The supported rates that the DETECTED_RATE bits can output are shown in Table 4-2 below.

Table 4-2: Automatic Rate Detection - Supported Data Rates

DETECTED_RATE	Data Rate
000	125Mb/s – MADI
001	270Mb/s – SD
010	1.485Gb/s – HD
011	2.97Gb/s – 3G
100	5.94Gb/s – 6G

4.3.4 Low/High Bit Rate Detection for Slew Rate Control

A status output named LBR_HBR is provided to control the slew rate selection input of a downstream SDI cable driver. It can be connected to the SD_EN input of drivers such as the GS6080 or GS6081 using the Semtech recommended application circuit.

When this signal is HIGH, the data rate is 270Mb/s (SD) or 125Mb/s (MADI). This signal is LOW for all other supported data rates, and when the GS6150 is operating in Bypass Mode or any time the device is not locked.

The LBR_HBR output signal is available to the application on any of the GPIO[3:0] multifunction status and control pins. It is selected for output using the GPIO[3:0]_IO_SELECT and GPIO[3:0]_SELECT bits accessible in the GPIO_CONTROL_REG_0 and GPIO_CONTROL_REG_1 registers. By default, LBR_HBR is output on GPIO2.

4.4 Low Power Modes

The device can be programmed via the GSPI to operate in two different low power modes. SLEEP mode has minimum power consumption at the expense of recovery time upon de-assertion of the FORCE_PWRDN_SLEEP bit. STANDBY mode has higher power consumption relative to SLEEP mode but minimizes time to return to operation on deassertion of the FORCE_PWRDN_STANDBY bit. The features affected by each mode are outlined below.

SLEEP mode:

- LOS detection remains functional
- The GSPI remains functional
- The reference oscillator remains functional

STANDBY mode:

- LOS detection remains functional
- The GSPI remains functional
- The reference oscillator remains functional
- The VCO and PLL remains functional so as to minimize the lock time when a signal is detected
- The rate detector remains set to the last valid data rate. On detection of a signal, the last valid rate is tested first by the rate detect state machine

The device can be programmed to automatically enter into SLEEP or STANDBY mode when LOS is asserted by programming the AUTO_PWRDN_DISABLE bit in the PWRDN_CONTROL register at address 17_h. The AUTO_PWRDN_MODE bit in the same register selects which mode, SLEEP or STANDBY, is entered into upon assertion of LOS.

GS6150
Final Data Sheet Rev.2
PDS-060127 March 2015

4.5 Serial Data Output

The GS6150 has two current-mode differential output drivers, each capable of driving up to $1V_{pp}$ differential into an external 100Ω differential load.

The output drivers operate with any binary coded signal with supported data rates up to 5.94Gb/s. This is applicable to both the serial data (DDO, \overline{DDO}) and serial data (DDO1, $\overline{DDO1}$) outputs of the device.

4.5.1 Output Impedance

Each of the GS6150's output buffers include two on-chip, 50Ω termination resistors.

4.5.2 Output Signal Interface Levels

The serial digital outputs operate within specification with an output CML power supply of 1.2V to 2.5V.

4.5.3 Adjustable Output Swing

Through the GSPI, the output swing can be set in the range from approximately 230mV_{ppd} to 930mV_{ppd} in 45mV_{ppd} increments, when the outputs are terminated with 50Ω loads. For the exact values, please see Table 4-3 below.

The output swing for each data rate is controlled using the bits in the DRIVER_CONTROL_REG_3, DRIVER_CONTROL_REG_4, DRIVER_CONTROL_REG_5, and DRIVER_CONTROL_REG_6 registers at addresses 1C_h through 1F_h.

The device automatically adjusts the swing setting depending on the state of the device (i.e. detected rate, bypass mode, or mute). There are separate register controls for mute, bypass and each data rate.

Table 4-3: Serial Digital Output Swing Settings

Register Setting (See Note 1)	Min	Тур	Max	Units
0000 _b	175	230	290	mV
0001 _b	205	275	345	mV
0010 _b	245	325	405	mV
0011 _b (default)	280	370	460	mV
0100 _b	310	410	510	mV
0101 _b	345	460	575	mV
0110 _b	380	510	640	mV
0111 _b	420	560	700	mV

Table 4-3: Serial Digital Output Swing Settings (Continued)

Register Setting (See Note 1)	Min	Тур	Max	Units
1000 _b	455	605	760	mV
1001 _b	490	655	820	mV
1010 _b	530	705	880	mV
1011 _b	565	755	945	mV
1100 _b	600	800	1000	mV
1101 _b	630	840	1050	mV
1110 _b	670	890	1110	mV
1111 _b	700	930	1160	mV

Note:

 Applicable registers that can be programmed with the values shown above are DD00_SWING_1G485, DD00_SWING_270M, DD00_SWING_125M, DD00_SWING_BYPASS, DD00_SWING_MUTE, DD00_SWING_5G94, DD00_SWING_2G97, DD01_SWING_1G485, DD01_SWING_270M, DD01_SWING_125M, DD01_SWING_BYPASS, DD01_SWING_MUTE, DD01_SWING_5G94, and DD01_SWING_2G97

4.5.4 Output De-emphasis

The GS6150 features adjustable output de-emphasis to compensate for PCB dielectric trace loss. Each output can be independently set to a different de-emphasis setting for each detected rate through controls found in the DRIVER_CONTROL_REG_1 and DRIVER_CONTROL_REG_2 registers.

The effect of de-emphasis, illustrated in Figure 4-3, is to attenuate the swing of bits that do not follow a bit transition (V_{DE}). The swing of bits that do follow a bit transition (V_{nom}) is set by the output swing registers found in Section 4.5.3 and do not depend on the de-emphasis settings.

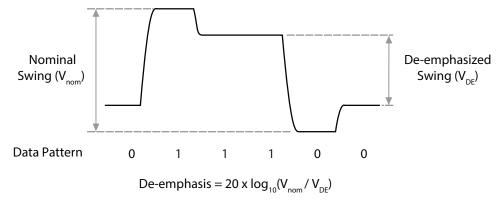


Figure 4-3: De-emphasis Waveform